NSN 5961-01-212-7307



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-212-7307 **Inclosure Material:** Metal **Overall Length:** 0.700 inches Overall Diameter: 0.300 inches **End Application:** Satellite communications set, an/wsc- (v) 9 **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 4.0 emitter to base voltage, static, collector open and 33.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 2.20 amperes source cutoff current **Power Rating Per Characteristic:** 55.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Leads gold **Precious Material:** Gold **Thread Series Designator:** Unc

N/a

4 ribbon **Shelf Life:**

Terminal Type And Quantity:

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Demilitarization:

No

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